

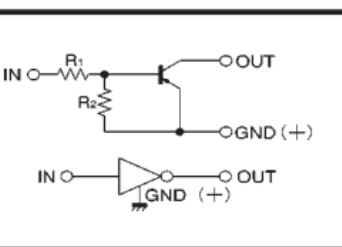
# Digital transistors (built-in resistors)

DTA114WE / DTA114WUA / DTA114WKA / DTA114WSA

## ●Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on / off conditions need to be set for operation, making device design easy.
- 4) Higher mounting densities can be achieved.

## ●Circuit schematic



## ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>	—	—	-0.8	V	V <sub>CC</sub> =-50V , I <sub>O</sub> =-100 μA
	V <sub>I(on)</sub>	-3	—	—	V	V <sub>O</sub> =-0.3V , I <sub>O</sub> =-2mA
Output voltage	V <sub>O(on)</sub>	—	-0.1	-0.3	V	I <sub>O</sub> =-10mA , I <sub>I</sub> =-0.5mA
Input current	I <sub>I</sub>	—	—	-0.88	mA	V <sub>I</sub> =-5V
Output current	I <sub>O(off)</sub>	—	—	-0.5	μA	V <sub>CC</sub> =-50V , V <sub>I</sub> =0V
DC current gain	G <sub>I</sub>	24	—	—	—	I <sub>O</sub> =-10mA , V <sub>O</sub> =-5V
Input resistance	R <sub>I</sub>	7	10	13	kΩ	—
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.37	0.47	0.57	—	—
Transition frequency	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> =-10V , I <sub>E</sub> =5mA , f=100MHz *

## ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V <sub>CC</sub>	-50	V
Input voltage	V <sub>I</sub>	-30~+10	V
Output current	I <sub>O</sub>	-100	
Power dissipation	I <sub>C(Max.)</sub>	-100	mA
	DTA114WE	150	
	DTA114WUA / DTA114WKA	200	
DTA114WSA	300		mW
	Junction temperature	T <sub>J</sub>	150 °C
	Storage temperature	T <sub>STG</sub>	-55~+150 °C

## ●Package, marking, and packaging specifications

Part No.	DTA114WE	DTA114WUA	DTA114WKA	DTA114WSA
Package	EMT3	UMT3	SMT3	SPT
Marking	74	74	74	—
Packaging code	TL	T106	T146	TP
Basic ordering unit (pieces)	3000	3000	3000	5000